



SSCTXXX22D2 Series

3.3V~24V Ultra Low Capacitance bi-directional TVS Diode

● Description

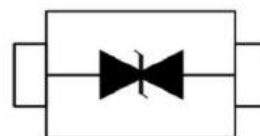
The SSCTXXX22D2 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines.

The SSCTXXX22D2 complies with the IEC 61000-4-2 (ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a leadfree SOD-323 package. The small size, low capacitance and high ESD surge protection make SSCTXXX22D2 an ideal choice to protect cell phone, wireless systems, and communication equipment.

● Feature

- ✧ 350W peak pulse power ($t_p = 8/20\mu\text{s}$)
- ✧ SOD-323 Package
- ✧ Working voltage: 3.3V, 5V, 12V, 15V, 24V, 36V
- ✧ Low clamping voltage
- ✧ Low capacitance
- ✧ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-4 (EFT) 40A (5/50ns)

● PIN configuration



Top view

● Applications

- ✧ Cell Phone Handsets and Accessories
- ✧ Microprocessor based equipment
- ✧ Personal Digital Assistants (PDA's)
- ✧ Notebooks, Desktops, and Servers
- ✧ Portable Instrumentation
- ✧ Networking and Telecom
- ✧ Serial and Parallel Ports.
- ✧ Peripherals

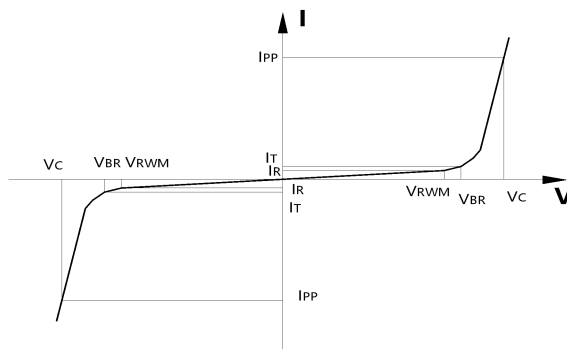
● Mechanical data

- ✧ Case Material: "Green" Molding Compound.
- ✧ UL Flammability Classification Rating 94V-0
- ✧ Qualified max reflow temperature: 260°C
- ✧ Device meets MSL 3 requirements
- ✧ Moisture Sensitivity: Level 3 per J-STD-020



● Electronic Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance



● Absolute maximum rating @ $T_A=25^{\circ}\text{C}$

SSCT3V322D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p=8/20\mu\text{s}$ waveform)	P_{PPP}	350	W
Peak Pulse Current ($t_p=8/20\mu\text{s}$ waveform)	I_{PP}	20	A
ESD Rating per IEC61000-4-2:	Contact	30	K
	Air	30	kV
Operating Temperature Range	T_J	-55 ~ 125	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ 150	$^{\circ}\text{C}$
SSCT5V022D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p=8/20\mu\text{s}$ waveform)	P_{PPP}	350	W
Peak Pulse Current ($t_p=8/20\mu\text{s}$ waveform)	I_{PP}	17	A
ESD Rating per IEC61000-4-2:	Contact	30	kV
	Air	30	kV
Operating Temperature Range	T_J	-55 ~ 125	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ 150	$^{\circ}\text{C}$
SSCT12V22D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power ($t_p=8/20\mu\text{s}$ waveform)	P_{PPP}	350	W
Peak Pulse Current ($t_p=8/20\mu\text{s}$ waveform)	I_{PP}	11	A
ESD Rating per IEC61000-4-2:	Contact	30	kV
	Air	30	kV
Operating Temperature Range	T_J	-55 ~ 125	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ 150	$^{\circ}\text{C}$



SSCTXXX22D2

SSCT15V22D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs waveform)	P _{PPP}	350	W
Peak Pulse Current (tp=8/20μs waveform)	I _{PP}	10	A
ESD Rating per IEC61000-4-2:	VESD	30	kV
Contact Air		30	
Operating Temperature Range	T _J	-55 ~ 125	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
SSCT24V22D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs waveform)	P _{PPP}	350	W
Peak Pulse Current (tp=8/20μs waveform)	I _{PP}	7	A
ESD Rating per IEC61000-4-2:	VESD	30	kV
Contact Air		30	
Operating Temperature Range	T _J	-55 ~ 125	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
SSCT36V22D2			
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs waveform)	P _{PPP}	350	W
Peak Pulse Current (tp=8/20μs waveform)	I _{PP}	5	A
ESD Rating per IEC61000-4-2:	VESD	30	kV
Contact Air		30	
Operating Temperature Range	T _J	-55 ~ 125	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C

● Electrical Characteristics @T_A=25°C

SSCT3V322D2						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}				3.3	V
Breakdown Voltage	V _{BR}	I _T = 1mA	4.0			V
Reverse Leakage Current	I _R	V _{RWM} = 3.3V			40	uA
Clamping Voltage	V _C	IPP = 1A , tp = 8/20us		7		V
Clamping Voltage	V _C	IPP = 20A, tp = 8/20us			19	V
Junction Capacitance	C _J	VR = 0V, f = 1MHz		450		pF

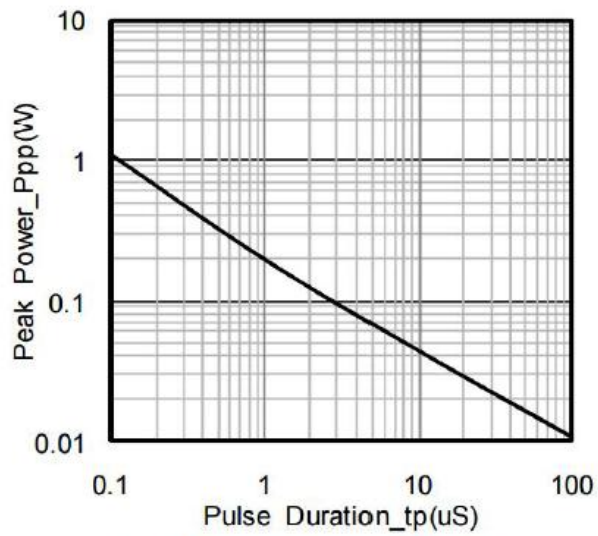


SSCTXXX22D2

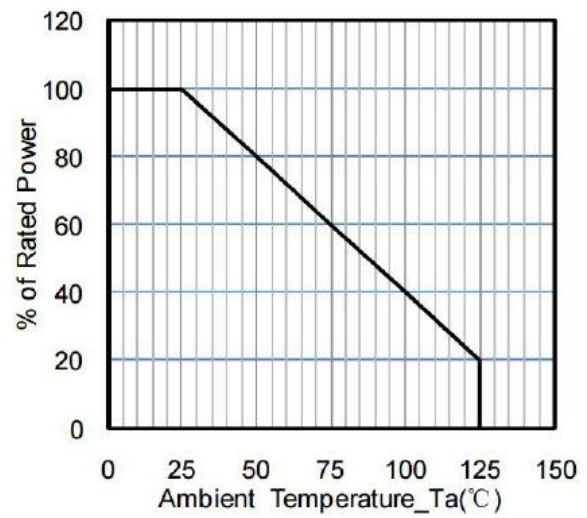
SSCT5V022D2						
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				5	V
Breakdown Voltage	V_{BR}	$I_T = 1mA$	6			V
Reverse Leakage Current	I_R	$V_{RWM} = 5V$			10	μA
Clamping Voltage	V_C	$I_{PP} = 1A$, $t_p = 8/20\mu s$		9.8		V
Clamping Voltage	V_C	$I_{PP} = 17A$, $t_p = 8/20\mu s$			21	V
Junction Capacitance	C_J	$V_R = 0V$, $f = 1MHz$		200		pF
SSCT12V22D2						
Parameter	Symbol		Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				12	V
Breakdown Voltage	V_{BR}	$I_T = 1mA$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM} = 12V$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1A$, $t_p = 8/20\mu s$		19		V
Clamping Voltage	V_C	$I_{PP} = 11A$, $t_p = 8/20\mu s$			32	V
Junction Capacitance	C_J	$V_R = 0V$, $f = 1MHz$		75		pF
SSCT15V22D2						
Parameter	Symbol		Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				15	V
Breakdown Voltage	V_{BR}	$I_T = 1mA$	16.7			V
Reverse Leakage Current	I_R	$V_{RWM} = 15V$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1A$, $t_p = 8/20\mu s$		24		V
Clamping Voltage	V_C	$I_{PP} = 10A$, $t_p = 8/20\mu s$			38	V
Junction Capacitance	C_J	$V_R = 0V$, $f = 1MHz$		68		pF
SSCT24V22D2						
Parameter	Symbol		Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				24	V
Breakdown Voltage	V_{BR}	$I_T = 1mA$	26.7			V
Reverse Leakage Current	I_R	$V_{RWM} = 24V$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1A$, $t_p = 8/20\mu s$		43		V
Clamping Voltage	V_C	$I_{PP} = 7A$, $t_p = 8/20\mu s$			52	V
Junction Capacitance	C_J	$V_R = 0V$, $f = 1MHz$		57		pF
SSCT36V22D2						
Parameter	Symbol		Min	Typ	Max	Unit
Reverse Working Voltage	V_{RWM}				36	V
Breakdown Voltage	V_{BR}	$I_T = 1mA$	40			V
Reverse Leakage Current	I_R	$V_{RWM} = 36V$			1	μA
Clamping Voltage	V_C	$I_{PP} = 1A$, $t_p = 8/20\mu s$		63		V
Clamping Voltage	V_C	$I_{PP} = 5A$, $t_p = 8/20\mu s$			80	V
Junction Capacitance	C_J	$V_R = 0V$, $f = 1MHz$		35		pF



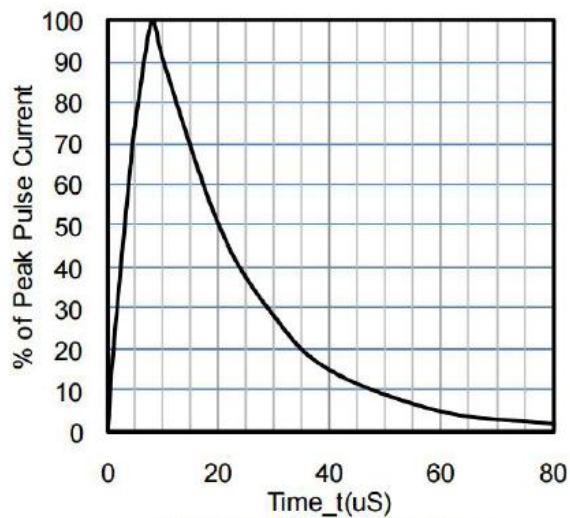
- Typical Performance Characteristics



Peak Pulse Power vs. Pulse Time



Power Derating Curve



8 X 20uS Pulse Waveform



● Package Information

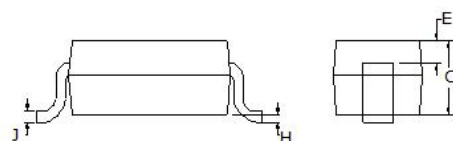
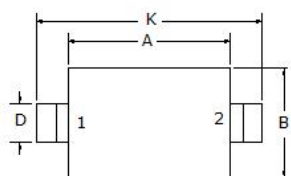
Ordering Information

Device	Making	Package	Qty per Reel	Reel Size
SSCT3V322D2	03B	SOD-323	3000	7 Inch
SSCT5V022D2	05B	SOD-323	3000	7 Inch
SSCT12V22D2	12B	SOD-323	3000	7 Inch
SSCT15V22D2	15B	SOD-323	3000	7 Inch
SSCT24V22D2	24B	SOD-323	3000	7 Inch
SSCT36V22D2	36B	SOD-323	3000	7 Inch

Mechanical Data

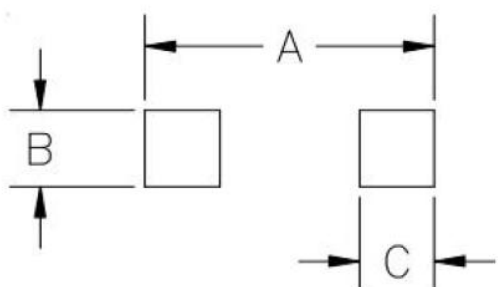
Case: SOD-323

Case Material: Molded Plastic. UL Flammability



Dim	Dimensions			
	Millimeters		Inches	
	Min	Max	Min	Max
A	1.50	1.80	0.060	0.071
B	1.2	1.40	0.045	0.054
C	-	1.10	-	0.043
D	0.30	0.40	0.012	0.016
H	-	0.10	-	0.004
J	0.10	0.25	0.004	0.010
K	2.30	2.70	0.090	0.107

Recommended Pad outline



Dim	Dimensions	
	Millimeter	Inches
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031



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